1.65" 240*295 IPS ST7789V3 262K 8 Bit B2B 24 Pin Connector

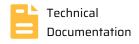
4 ALP ELECTRONIX



- ST7789V3 is driven with 18 bit color depth.
- Single chip TFT-LCD Controller/Driver with On-chip Frame Memory (FM).
- Display Features
 - Programmable Partial Display Duty
 - CABC for saving current consumption
- · Driving Algorithm
 - Dot Inversion.
 - Column Inversion.
 - Color enhancement.
- LCD can display 262K Colors (6R:6G:6B).
- LCD Interface
 - "8 Bits parallel interface..
- Normally black.
- IPS, all view direction.
- Power Supply
 - VDD: 2.4V 3.3V.
 - Brightness: 500 cd/m².
- Low Profile Board-to-Board Connector.







1 General Specifications

No.	Item	Contents	Unit
1	LCD size	1.65	inch
2	Display mode	Normally black	-
3	Resolution	240(H)RGB x 295(V)	pixels
4	Pixel pitch	0.108(H) x 0.108(V)	mm
5	Active area	25.92(H) x 31.86(V)	mm
6	Module size	28.13(H) x 36.93(V) x 1.5 (D)	mm
7	Pixel arrangement	RGB vertical stripe	-
8	Interface	8 Bits 8080 MCU	-
9	Display colors	262K	colors
10	Driver IC	ST7789V3	-
11	Luminance	500 (TYP)	cd/m²
12	Viewing direction	All view	-
13	Backlight	3 white LED parallel	-
14	Operating temperature	-20°C - +70°C	-
15	Storage temperature	-30°C - +80°C	-
16	Weight	3	gram

2 Electrical Characteristics

2.1 Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{DD}	-0.3	4.6	V
Operation Temperature	T _{OP}	-20	70	°C
Storage Temperature	T _{ST}	-30	80	°C

2.2 Operating Conditions

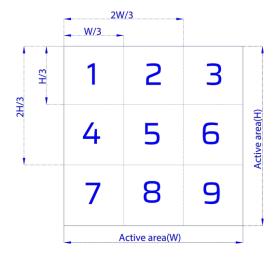
Parameter	Symbol	Min.	Тур.	Max.	Unit
Supply Voltage (IO)	V _{DD}	2.4	2.8	3.3	V
Gate Driver High Voltage	V _{GH}	12.2	-	14.97	V
Gate Driver Low Voltage	V _{GL}	-12.5	-	-7.16	V
Operating Current For VDD	I _{DD}	-	8	10	mA
Sleep_in Mode (VDD)	I _{DD}	-	15	30	μΑ

2.3 Backlight Unit

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Voltage for LED backlight	V _{LED}	2.8	3.0	3.2	V	
Current for LED backlight	I _{LED}	-	60	90	mA	3 LED
Power Consumption ¹	P _{bl}	-	180	288	mW	1
Brightness ²	-	450	500	-	cd/m²	2
LED Life Time ³		20000	-	-	hr	3

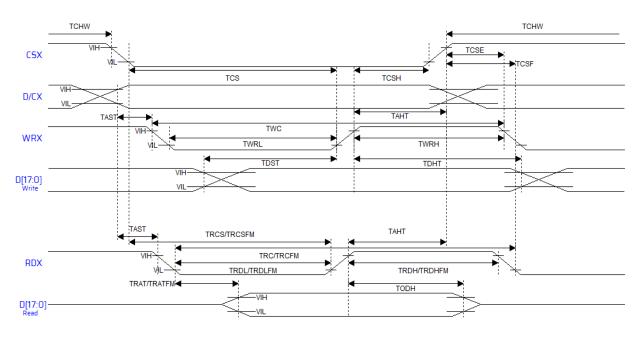
Notes:

- 1. Where I_{LED} = 60mA, V_{LED} = 3.0V, $P_{CONSUMPTION}$ = I_{LED} * V_{LED} .
- 2. Uniform measure condition:
 - a) Measure 9 point, measure location is shown on the right side.
 - b) Uniform = (Min. brightness / Max brightness) * 100%
 - c) Best contrast.
- 3. The environmental test has been conducted under ambient air flow at T_A = 25±2°C, 60%RH±5%.



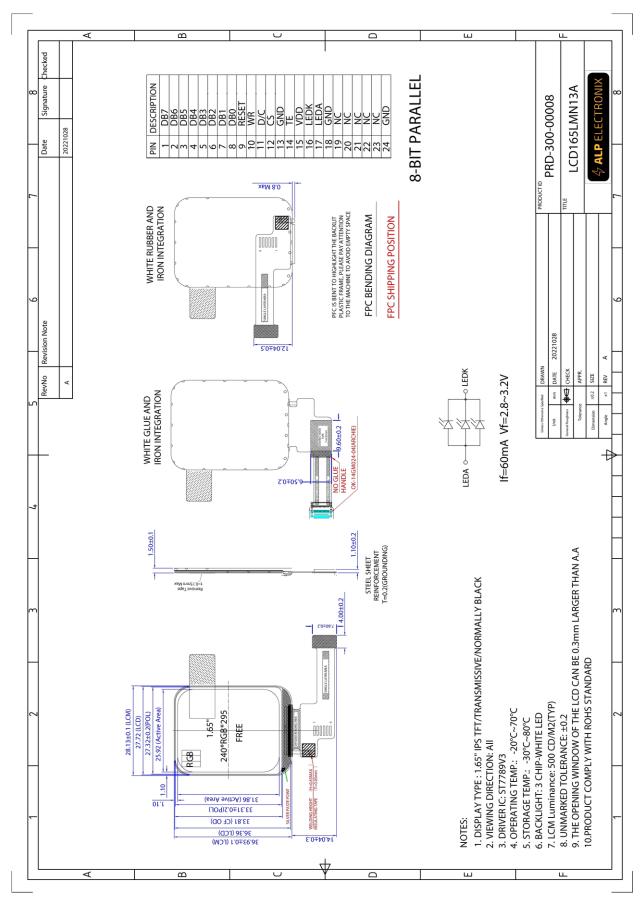
2.4 Timing Characteristic of The LCD

2.4.1 8080 Series MCU Parallel interface Characteristics:



Signal	Signal Symbol Parameter		Min	Max.	Unit	Description
D/CX	T _{AST}	Address setup time	0	-	ns	
D/CX	T _{AHT}	Address hold time (Write/Read)	10	-	ns	-
	T _{CHW}	Chip select "H" pulse width	0	-	ns	
	T _{cs}	Chip select setup time (Write)	15	-	ns	
CSX	T _{RCS}	Chip select setup time (Read ID)	45	-	ns	
CSX	T _{RCSFM}	Chip select setup time (Read FM)	355	-	ns	-
	T _{CSF}	Chip select wait time (Write/Read)	10	-	ns	
	T _{CSH}	Chip select hold time	10	-	ns	
	T _{wc}	Write cycle	66	-	ns	
WRX	T _{WRH}	Control pulse "H" duration	15	-	ns	-
	T _{WRL}	Control pulse "L" duration	15	-	ns	
	T _{RC}	Read cycle (ID)	160	-	ns	
RDX (ID)	T _{RDH}	Control pulse "H" duration (ID)	90	-	ns	When read ID data
	T _{RDL}	Control pulse "L" duration (ID)	45	-	ns	
	T _{RCFM}	Read cycle (FM)	450	-	ns) A/I I
RDX (FM)	T _{RDHFM}	Control pulse "H" duration (FM)	90	-	ns	When read from frame memory
	T _{RDLFM}	Control pulse "L" duration (FM)	355	-	ns	
D[17:0]	D[17:0] T _{DST} Data setup time		10	-		For CL=30pF

3 Mechanical Drawing



4 Pin Definition

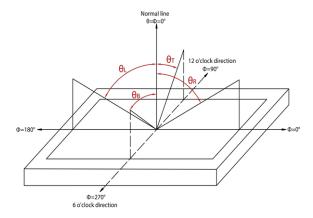
Pin no.	Symbol	Description		
1	DB7	MCU parallel interface data.		
2	DB6	MCU parallel interface data.		
3	DB5	MCU parallel interface data.		
4	DB4	MCU parallel interface data.		
5	DB3	MCU parallel interface data.		
6	DB2	MCU parallel interface data.		
7	DB1	MCU parallel interface data.		
8	DBO	MCU parallel interface data.		
9	RESET	Reset signal. It must be applied to properly initialize the chip. Active low.		
10	WR	Write enable in MCU parallel interface.		
11	D/C	Display data/command selection pin.		
12	<u>CS</u>	Chip select pin. Active low.		
13	GND	Ground pin.		
14	TE	Tearing effect signal is used to synchronize MCU to frame memory writing		
15	VDD	Power supply pin, VDD=2.5-3.3V.		
16	LEDK	Backlight LED cathode pin.		
17	LEDA	Backlight LED anode pin.		
18	GND	Ground pin.		
19 - 23	NC	No connection.		
24	GND	Ground pin.		

5 Optical Characteristics

Item	Symbol	Measuring	g Conditions	Min.	Typ.	Max.	Unit	Remark
	θ	Φ = 0°	25°C	75	80	-	- Degree	Note 1
Viewing Angle ¹		Φ = 180°	25°C	75	80	-		
viewing Angle	θ	Φ = 90°	25°C	75	80	-		
	•	Ф = 270°	25°C	75	80	-		
Brightness	L _{br}		-	450	500	-	cd/m²	
Luminance Uniformity	ΔL		1	70	75			
Contrast Ratio ²	CR	-	25°C	700	900	-		Note 2
Response Time	T _R +T _F	$\theta = 0^{\circ}$ $\Phi = 0^{\circ}$	25°C	-	30	35	mS	
	White Red	X	25°C		0.288	+0.03	-	BM-7A
		Υ	25°C		0.312			
		X	25°C		0.602			
Color of CIE Coordinate	Reu	Υ	25°C	-0.03	0.348			
Color of the coordinate	Green	X	25°C	-0.03	0.321			
	Green	Υ	25°C		0.576			
	Blue	X	25°C		0.156			
	Diue	Υ	25°C		0.107			
Transmittance (with polarizer)				4.3	5.0	-	%	

Notes:

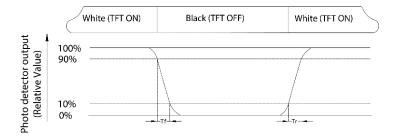
1. Definition of Viewing Angle:



2. Definition of Contrast Ratio (CR): measured at the center point of panel

 $Contrast\ Ratio\ (CR) = \frac{Luminance\ measured\ when\ LCD\ is\ on\ the\ White\ state}{Luminance\ measured\ when\ LCD\ is\ on\ the\ Black\ state}$

3. Definition of Response Time: Sum of T_R and T_F



6 Reliability

6.1 Contents of Reliability Tests

No.	Item	Conditions					
1	High Temperature Operation	70°C ±2°C, 120 hrs					
2	Low Temperature Operation	-20°C ±2°C, 120 hrs					
3	High Temperature Storage	80°C ±2°C, 120 hrs					
4	Low Temperature Storage	-30°C ±2°C, 120 hrs					
5	High Temperature	60°C ±2°C, 90% RH, 120 hrs					
	/Humidity Operation	00 C 12 C, 30% KH, 120 IIIS					
		-10°C→25°C→60°C→25°C→-10°C					
6	Temperature Cycling	30min 5min 30min 5min 30min					
		10 cycle.					
		Total fixed amplitude:1.5mm.					
7	Vibration Test	Vibration Frequency:10~55Hz					
		One cycle 60 seconds to 3 direction of X, Y, Z each 15 minutes.					
8	ESD Test	Air Discharge: ±4KV with 5 times.					
	בסח נפצו	Contact Discharge: ±2KV with 5 times.					

Note: No charge on display and in operation under the following test condition. Please note that the reliability test project requires the use of virgin samples.

Condition: Unless otherwise specified ,tests will be conducted under the following condition.

Temperature:20°C ±5°C.

Humidity:65±5%RH.

Tests will be not conducted under functioning state.

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7 Revision History

Revision	Details
1.0	Initial Release – 01.01.2023

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